High Reliability ICL76XX Series Low Power CMOS Operational Amplifiers

GENERAL DESCRIPTION

The ICL761X/762X/764X series is a family of monolithic CMOS operational amplifiers. These devices provide the designer with high performance operation at low supply voltages and selectable quiescent currents, and are an ideal design tool when ultra low input current and low power dissipation are desired.

The basic amplifier will operate at supply voltages ranging from \pm 1V to \pm 8V, and may be operated from a single Lithium cell

A unique quiescent current programming pin allows setting of standby current to 1mA, $100\mu A$, or $10\mu A$, with no external components. This results in power consumption as $10\mu A$. Output swings range to within a few millivolts of the supply voltages.

Of particular significance is the extremely low (1pA) input current, input noise current of .01pA/ $\sqrt{\text{Hz}}$, and $10^{12}\Omega$ input impedance. These features optimize performance in very high source impedance applications.

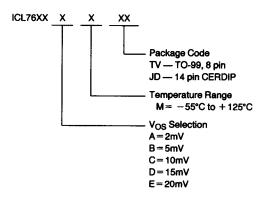
The inputs are internally protected and require no special handling procedures. Outputs are fully protected against short circuits to ground or to either supply.

AC performance is excellent, with a slew rate of 1.6V/ μ s, and unity gain bandwidth of 1MHz at I_{O} = 1mA.

Because of the low power dissipation, operating temperatures and drift are quite low. Applications utilizing these features may include stable instruments, extended life designs, or high density packages.

SELECTION GUIDE

DEVICE NOMENCLATURE



FEATURES

- Wide Operating Voltage Range ± 1V to ±8V
- High Input Impedance 10¹²Ω
- ullet Programmable Power Consumption Low As $20 \mu W$
- Input Current Lower Than BIFETs Typ 1pA
- Available As Singles, Duals, and Quads
- Output Voltage Swings to Within Millivolts Of V⁻ and V⁺
- Low Power Replacement for Many Standard Op Amps
- Compensated and Uncompensated Versions
- Input Common Mode Voltage Range Greater Than Supply Rails (ICL7612)

APPLICATIONS

- Portable Instruments
- Telephone Headsets
- Hearing Aid/Microphone Amplifiers
- Meter Amplifiers
- Medicai Instruments
- High Impedance Buffers

SPECIAL FEATURE CODES

C = INTERNALLY COMPENSATED

H = HIGH QUIESCENT CURRENT (1mA)
L = LOW QUIESCENT CURRENT (10µA)

M = MEDIUM QUIESCENT CURRENT (100μA)

O = OFFSET NULL CAPABILITY

P = PROGRAMMABLE QUIESCENT CURRENT

V = EXTENDED CMVR

ORDERING INFORMATION

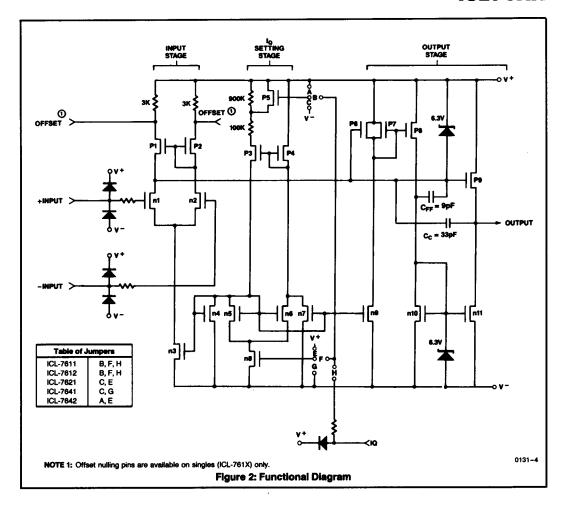
	Number of	Package Typ	pe and Suffix		
Basic Part	OP-AMPS in Package, and Special Features	8-Lead TO-99	Ceramic DIP (1)		
(SEE CODES)	−55°C to + 125°C	−55°C to + 125°C			
	SINGLE OP-AMP:				
ICL7611	C, O, P	AMTV			
ICL7612	C, O, P, V	BMTV			
		DMTV			
	DUAL OP-AMP:	AMTV			
ICL7621	C, M	BMTV			
	·	DMTV			
	QUAD OP-AMP:				
ICL7641	С, н				
ICL7642	C, L		CMJD		
			EMJD		
	1	1			

NOTES: 1. Duals and quads are available in 14 pin DIP package.

2. Ordering code must consist of basic part number and package suffix, e.g., ICL7611BCPA.

Device	Description	Pin Assignments
ICL7611XMTV ICL7612XMTV	Internal compensation, plus offset null capability and external I _Q control	TO-99 (TOP VIEW) (outline dwg TV) OFFSET 1 8 7 V* -IN 2 6 OUTPUT -IN 3 4 5 OFFSET

Device	Description	Pin Assignments
ICL7621XMTV	Dual op amps with internal compensation; I _Q fixed at 100 µA Pin compatible with Texas Inst. TL082 Motorola MC1458 Raytheon RC4558	TO-99 (TOP VIEW) (outline dwg TV) OUT, 1
		°Pin 8 connected to case.
ICL7641XMJD ICL7642XMJD	Quad op amps with internal compensation. IQ fixed at 1mA (ICL7641) IQ fixed at 10µA (ICL7642) Pin compatible with Texas Instr. TL084 National LM324 Harris HA4741	14 PIN DIP (TOP VIEW) (outline dwg JD, PD) OUT ₀ -IN ₀ +IN ₀ V +IN ₀ -IN ₀ OUT ₀ 14 13 12 11 10 9 8 OUT _A -IN _A +IN _A V +IN _B -IN _B OUT ₀ OUT _A -IN _A +IN _A V +IN _B -IN _B OUT ₀
	Figure 1: Pin Configure	



ABSOLUTE MAXIMUM RATINGS

Total Supply Voltage V+ to V 18V
Input Voltage
Differential Input Voltage [1] $\pm [(V^+ + 0.3) - (V^ 0.3)]V$
Duration of Output Short Circuit ^[2] Unlimited

Continuous Power Dissipation

	@25°C	Above 25°C
	@25 C	derate as below:
TO-99	250mW	2mW/°C
8 Lead Minidip	250mW	2mW/°C
14 Lead CERDIP	500mW	4mW/°C
16 Lead Plastic	375mW	3mW/°C
Storage Temperature F Operating Temperature		65°C to +150°C
ICL76XXM	.	55°C to +125°C
Lead Temperature (Sol	dering, 10sec)	

NOTE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

NOTE 1. Long term offset voltage stability will be degraded if large input differential voltages are applied for long periods of time.

2. The outputs may be shorted to ground or to either supply, for V_{SUPP} ≤ 10V. Care must be taken to insure that the dissipation rating is not exceeded.

ELECTRICAL CHARACTERISTICS (7611/12 and 7621 ONLY)

 $(V_{SUPPLY} = \pm 5.0V, T_A = 25^{\circ}C, unless otherwise specified.)$

Symbol	ol Parameter Test Conditions 76XX		A	76XXB			76XXD			Units		
-	T dramoto:	Tost conditions	Min Typ Max		Min	Тур	Max	Min	Тур	Max		
v _{os}	Input Offset Voltage	$R_S \le 100k\Omega$, $T_A = 25^{\circ}C$ $T_{MIN} \le T_A \le T_{MAX}$			2 3			5 7			15 20	mV
ΔV _{OS} /ΔΤ	Temperature Coefficient of VOS	R _S ≤100kΩ		10			15			25		μV/°C
los	Input Offset Current	T _A = 25°C ΔT _A = M		0.5	30 800		0.5	30 800		0.5	30 800	рA
IBIAS	Input Bias Current	T _A =25°C ΔT _A =M		1.0	50 4000		1.0	50 4000		1.0	50 4000	рA
V _{CMR}	Common Mode Voltage Range (Except ICL7612)	$I_Q = 10\mu A^{(1)}$ $I_Q = 100\mu A$ $I_Q = 1mA^{(1)}$	±4.4 ±4.2 ±3.7			±4.4 ±4.2 ±3.7			±4.4 ±4.2 ±3.7			٧
V _{CMR}	Extended Common Mode	I _Q =10μΑ	±5.3			±5.3			±5.3			
	Voltage Range (ICL7612 Only)	i _Q =100μA	+5.3 -5.1			+ 5.3 -5.1			+5.3 -5.1			v
		I _Q =1mA	+5.3 -4.5			+5.3 -4.5			+5.3 -4.5			
V _{OUT}	Output Voltage Swing	(1) $I_Q = 10\mu A$, $R_L = 1M\Omega$ $T_A = 25^{\circ}C$ $\Delta T_A = M$	±4.9 ±4.7			±4.9 ±4.7			± 4.9 ± 4.7			
		$I_Q = 100\mu A$, $R_L = 100k\Omega$ $T_A = 25^{\circ}C$ $\Delta T_A = M$	±4.9 ±4.5			±4.9 ±4.5			±4.9 ±4.5			٧
		(1) $I_Q = 1 \text{mA}$, $R_L = 10 \text{k}\Omega$ $T_A = 25^{\circ}\text{C}$ $\Delta T_A = \text{M}$	±4.5 ±4.0			±4.5 ±4.0			±4.5 ±4.0			

ELECTRICAL CHARACTERISTICS (7611/12 and 7621 ONLY) (Continued)

($V_{SUPPLY} = \pm 5.0V$, $T_A = 25$ °C, unlèss otherwise specified.)

Symbol	Parameter	Test Conditions		76XXA			76XX	3	76XXD			Units
OyDO.	T diamotor	Tool oonalions	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
Avol	Large Signal Voltage Gain	$V_O = \pm 4.0V$, $R_L = 1M\Omega$ $I_Q = 10\mu A^{(1)}$, $T_A = 25^{\circ}C$ $\Delta T_A = M$	86 74	104		80 68	104		80 68	104		
		$V_{Q} = \pm 4.0V$, $R_{L} = 100k\Omega$ $I_{Q} = 100\mu A$, $T_{A} = 25^{\circ}C$ $\Delta T_{A} = M$	86 74	102		80 68	102		80 68	102		dB
		$V_O = \pm 4.0V$, $R_L = 10k\Omega$ $I_Q = 1 \text{mA}^{(1)}$, $T_A = 25^{\circ}\text{C}$ $\Delta T_A = M$	80 72	83		76 68	83		76 68	83		
GBW	Unity Gain Bandwidth	$I_Q = 10 \mu A^{(1)}$ $I_Q = 100 \mu A$ $I_Q = 1 m A^{(1)}$		0.044 0.48 1.4			0.044 0.48 1.4			0.044 0.48 1.4		MHz
R _{IN}	Input Resistance			1012			1012			1012		Ω
CMRR	Common Mode Rejection Ratio	$R_S \le 100 k\Omega$, $I_Q = 10 \mu A^{(1)}$ $R_S \le 100 k\Omega$, $I_Q = 100 \mu A$ $R_S \le 100 k\Omega$, $I_Q = 1 m A^{(1)}$	76 76 66	96 91 87		70 70 60	96 91 87		70 70 60	96 91 87		dB
PSRR	Power Supply Rejection Ratio	$R_S \le 100 k\Omega$, $I_Q = 10 \mu A^{(1)}$ $R_S \le 100 k\Omega$, $I_Q = 100 \mu A$ $R_S \le 100 k\Omega$, $I_Q = 1 m A^{(1)}$	80 80 70	94 86 77		80 80 70	94 86 77		80 80 70	94 86 77		dB
en	Input Referred Noise Voltage	$R_S = 100\Omega$, $f = 1kHz$		100			100			100		nV/1∕Hz
in	Input Referred Noise Current	$R_S = 100\Omega$, $f = 1kHz$		0.01			0.01			0.01		pA/√Hz
SUPPLY	Supply Current (Per Amplifier)	No Signal, No Load I _Q SET = +5V(1) I _Q SET = 0V I _Q SET = -5V(1)			0.02 0.25 2.5		0.01 0.1 1.0	0.02 0.25 2.5		0.01 0.1 1.0	0.02 0.25 2.5	mA
V ₀₁ /V ₀₂	Channel Separation	A _{VOL} = 100		120			120			120		dB
SR		$A_{VOL} = 1$, $C_L = 100pF$ $V_{IN} = 8Vp-p$ $I_Q = 10\mu A(1)$, $R_L = 1M\Omega$ $I_Q = 100\mu A$, $R_L = 100k\Omega$ $I_Q = 1mA(1)$, $R_L = 10k\Omega$		0.016 0.16 1.6			0.016 0.16 1.6			0.016 0.16 1.6		V/μs
t _r	Rise Time	$V_{IN} = 50 \text{mV}, C_L = 100 \text{pF}$ $I_Q = 10 \mu \text{A}^{(1)}, R_L = 1 \text{M} \Omega$ $I_Q = 100 \mu \text{A}, R_L = 100 \text{k} \Omega$ $I_Q = 1 \text{mA}^{(1)}, R_L = 10 \text{k} \Omega$		20 2 0.9			20 2 0.9			20 2 0.9		μs
		$\begin{split} &V_{IN}\!=\!50\text{mV},C_L\!=\!100\text{pF}\\ &I_Q\!=\!10\mu\text{A}^1,R_L\!=\!1\text{M}\Omega\\ &I_Q\!=\!100\mu\text{A},R_L\!=\!100\text{k}\Omega\\ &I_Q\!=\!1\text{mA}^1,R_L\!=\!10\text{k}\Omega \end{split}$		5 10 40			5 10 40			5 10 40		%

NOTES: 1. ICL7611, 7612 only.

M = Military Temperature Range: -55°C to +125°C

ELECTRICAL CHARACTERISTICS (7641/42 ONLY)

($V_{SUPPLY} = \pm 5.0V$, $T_A = 25$ °C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	7	6XXC (6)	7	Units		
		Took Containing	Min	Тур	Max	Min	Тур	Max	Ornits
Vos	Input Offset Voltage	$R_S \le 100k\Omega$, $T_A = 25^{\circ}C$ $T_{MIN} \le T_A \le T_{MAX}$			10 15			20 25	m∨
$\Delta V_{OS}/\Delta T$	Temperature Coefficient of VOS	R _S ≤100kΩ		20			30		
los	Input Offset Current	$T_A = 25^{\circ}C$ $\Delta T_A = M$		0.5	30 800		0.5	30 800	рA
IBIAS	Input Bias Current	T _A =25°C ΔT _A =M		1.0	50 4000		1.0	50 4000	рA
V _{CMR}	Common Mode Voltage Range	I _Q =10μA (ICL7642) I _Q =1mA (ICL7641)	±4.4 ±3.7			±4.4 ±3.7			٧
V _{OUT}	Output Voltage Swing	ICL7642 $I_Q = 10\mu A$, $R_L = 1M\Omega$ $T_A = 25^{\circ}C$ $\Delta T_A = M$	±4.9 ±4.7			±4.9 ±4.7			v
-		ICL7641 $I_Q = 1 \text{mA}, R_L = 10 \text{k}\Omega$ $T_A = 25^{\circ}\text{C}$ $\Delta T_A = M$	±4.5 ±4.0			±4.5 ±4.0			·
Avol	Large Signal Voltage Gain	ICL7642 $V_O = \pm 4.0V, R_L = 1M\Omega$ $I_Q = 10\mu A, T_A = 25^{\circ}C$ $\Delta T_A = M$	80 68	104		80 68	104		dВ
		ICL7641 $V_Q = \pm 4.0V$, $R_L = 10kΩ$ $I_Q = 1mA$, $T_A = 25°C$ $\Delta T_A = M$	76 68	98		76 68	98		aв
GBW	Unity Gain Bandwidth	I _Q = 10μA (ICL7642) I _Q = 1mA (ICL7641)		0.044 1.4			0.044 1.4		MHz
R _{IN}	Input Resistance			1012			1012		Ω
CMRR	Common Mode Rejection Ratio	$R_S \le 100k\Omega$, $I_Q = 10\mu A^{(1)}$ $R_S \le 100k\Omega$, $I_Q = 1mA^{(2)}$	70 60	96 87		70 60	96 87		dB

ELECTRICAL CHARACTERISTICS (7641/42 ONLY) (Continued)

($V_{SUPPLY} = \pm 5.0V$, $T_A = 25$ °C, unless otherwise specified.)

Symbol	Parameter	Test Conditions		76XXC	(6)		Units		
Symbol			Min	Тур	Max	Min	Тур	Max	Ointo
PSRR	Power Supply Rejection Ratio	$R_S \le 100k\Omega$, $I_Q = 10\mu A^{(1)}$ $R_S \le 100k\Omega$, $I_Q = 1mA^{(2)}$	80 70	94 77		80 70	94 77		dB
θn	Input Referred Noise Voltage	$R_S = 100\Omega$, $f = 1kHz$		100			100		nV/√ Hz
In	Input Referred Noise Current	$R_S = 100\Omega$, $f = 1kHz$		0.01			0.01		pA/1∕Hz
ISUPPLY	Supply Current (Per Amplifier)	No Signal, No Load 7642 ONLY I _Q = 10µA (ICL7642)		0.01	0.03		0.01 0.01	0.03	mA
		IQ = 1mA (ICL7641)		1.0	2.5		1.0	2.5	
V _{O1} /V _{O2}	Channel Separation	A _{VOL} = 100		120			120		dB
SR	Slew Rate	$A_{VOL} = 1, C_L = 100pF$ $V_{IN} = 8Vp-p$ $I_Q = 10\mu A^{(1)}, R_L = 1M\Omega$ $I_Q = 1mA^{(2)}, R_L = 10k\Omega$		0.016 1.6	-		0.016 1.6		V/µs
t _r	Rise Time	$V_{IN} = 50 \text{mV}, C_L = 100 \text{pF}$ $I_Q = 10 \mu A^{(1)}, R_L = 1 M \Omega$ $I_Q = 1 \text{mA}^{(2)}, R_L = 10 k \Omega$		20 0.9			20 0.9		μs
	Overshoot Factor	$V_{IN} = 50 \text{mV}, C_L = 100 \text{pF}$ $I_Q = 10 \mu A^{(1)}, R_L = 1 \text{M}\Omega$ $I_Q = 1 \text{m}A^{(2)}, R_L = 10 \text{k}\Omega$		5 40			5 40		%

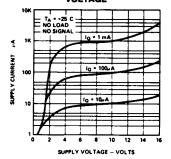
NOTES: 1. ICL7642 only. 2. ICL7641 only. For Test Conditions:

M = Military Temperature Range: -55°C to +125°C

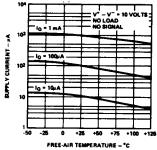
0131-7

TYPICAL PERFORMANCE CHARACTERISTICS

SUPPLY CURRENT PER AMPLIFIER AS A FUNCTION OF SUPPLY VOLTAGE



SUPPLY CURRENT PER AMPLIFIER AS A FUNCTION OF FREE-AIR TEMPERATURE



LARGE SIGNAL DIFFERENTIAL

VOLTAGE GAIN AND PHASE SHIFT AS A FUNCTION OF FREQUENCY

V_B

VOLTAGE GAM

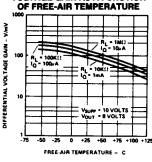
TA - +25°C

0131-6

0131-9

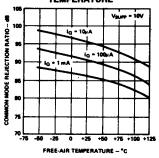
INPUT BIAS CURRENT AS A **FUNCTION OF TEMPERATURE** V* = +5 VOLTS NPUT BIAS 0.1 FREE-AIR TEMPERATURE - °C

LARGE SIGNAL DIFFERENTIAL **VOLTAGE GAIN AS A FUNCTION**



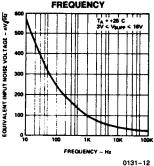
0131 - 8

COMMON MODE REJECTION RATIO AS A FUNCTION OF FREE-AIR **TEMPERATURE**

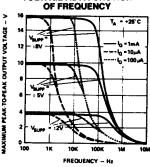




FREQUENCY - Hz

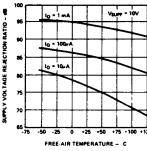






0131-13

POWER SUPPLY REJECTION RATIO AS A FUNCTION OF FREE-AIR **TEMPERATURE**

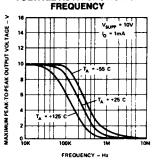


0131-11

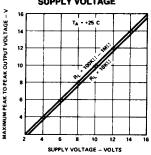
TYPICAL PERFORMANCE CHARACTERISTICS

0131-14

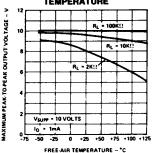
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE AS A FUNCTION OF



MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE AS A FUNCTION OF SUPPLY VOLTAGE

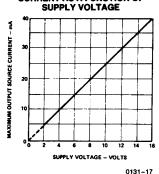


MAXIMUM PEAK-TO-PEAK VOLTAGE AS A FUNCTION OF FREE-AIR TEMPERATURE

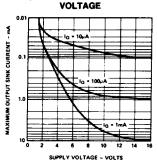


0131-16

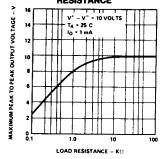
MAXIMUM OUTPUT SOURCE CURRENT AS A FUNCTION OF



MAXIMUM OUTPUT SINK CURRENT AS A FUNCTION OF SUPPLY

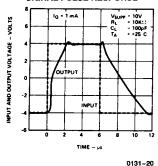


MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE AS A FUNCTION OF LOAD RESISTANCE

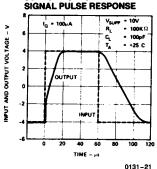


0131-19

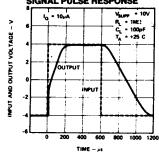
VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE



VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE



VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE



0131-22

DETAILED DESCRIPTION

Static Protection

All devices are static protected by the use of input diodes. However, strong static fields should be avoided, as it is possible for the strong fields to cause degraded diode junction characteristics, which may result in increased input leakage currents.

Latchup Avoidance

Junction-isolated CMOS circuits employ configurations which produce a parasitic 4-layer (p-n-p-n) structure. The 4-layer structure has characteristics similar to an SCR, and under certain circumstances may be triggered into a low impedance state resulting in excessive supply current. To avoid this condition, no voltage greater than 0.3V beyond the supply rails may be applied to any pin. In general, the op-amp supplies must be established simultaneously with, or before any input signals are applied. If this is not possible, the drive circuits must limit input current flow to 2mA to prevent latchup.

Choosing the Proper IQ

Each device in the ICL76XX family has a similar I_Q set-up scheme, which allows the amplifier to be set to nominal quiescent currents of $10\mu A$, $100\mu A$ or 1mA. These current settings change only very slightly over the entire supply voltage range. The ICL7611/12 have an external I_Q control terminal, permitting user selection of each amplifiers' quiescent current. The 7621 and 7641/42 have fixed I_Q settings (refer to selector guide for details.) To set the I_Q of programmable versions, connect the I_Q terminal as follows:

 $I_{\Omega} = 10 \mu A - I_{\Omega}$ pin to V+

 $I_Q = 100 \mu A - I_Q$ pin to ground. If this is not possible, any voltage from V⁺ -0.8 to V⁻ +0.8 can be used.

 $I_Q = 1 \text{mA} - I_Q \text{ pin to V}^-$

NOTE: The negative output current available is a function of the quiescent current setting. For maximum p-p output voltage swings into low impedance loads, I_Q of 1mA should be selected.

Output Stage and Load Driving Considerations

Each amplifiers' quiescent current flows primarily in the output stage. This is approximately 70% of the IQ settings. This allows output swings to almost the supply rails for output loads of $1 M \Omega$, $100 k \Omega$, and $10 k \Omega$, using the output stage in a highly linear class A mode. In this mode, crossover distortion is avoided and the voltage gain is maximized. However, the output stage can also be operated in Class AB for higher output currents. (See graphs under Typical Operating Characteristics). During the transition from Class A to Class B operation, the output transfer characteristic is non-linear and the voltage gain decreases.

A special feature of the output stage is that it approximates a transconductance amplifier, and its gain is directly proportional to load impedance. Approximately the same open loop gains are obtained at each of the l_{Ω} settings if corresponding loads of $10k\Omega$, $100k\Omega$, and $1M\Omega$ are used.

Input Offset Nulling

For ICL7611/12 models provided with OFFSET NULLING pins, nulling may be achieved by connecting a 25K pot between the OFFSET terminals with the wiper connected to V+. At quiescent currents of 1mA and 100 μ A, the nulling range provided is adequate for all V_{OS} selections; however with I_Q=10 μ A, nulling may not be possible with higher values of V_{OS}.

Frequency Compensation

The ICL76XX are internally compensated, and are stable for closed loop gains as low as unity with capacitive loads up to 100pF

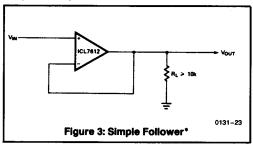
Extended Common Mode Input Range

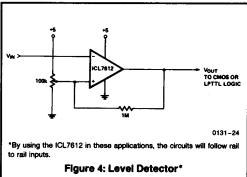
The ICL7612 incorporates additional processing which allows the input CMVR to exceed each power supply rail by 0.1 volt.

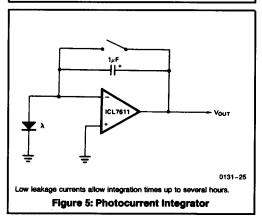
The user is cautioned that, due to extremely high input impedances, care must be exercised in layout, construction, board cleanliness, and supply filtering to avoid hum and noise pickup.

APPLICATIONS

Note that in no case is I_Q shown. The value of I_Q must be chosen by the designer with regard to frequency response and power dissipation.







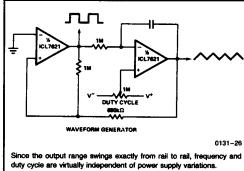


Figure 6: Precise Triangle/Square Wave Generator

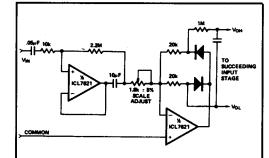
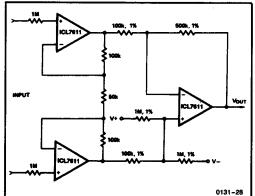
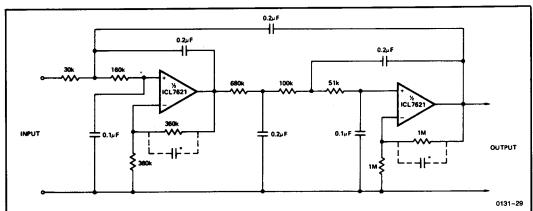


Figure 7: Averaging AC to DC Converter for A/D Converters Such as ICL7106, 7107, 7109, 7116, 7117



Note that A_{VOL} =25; single Ni-cad battery operation. Input current (from sensors connected to patient) limited to $<5\mu$ A under fault conditions

Figure 8: Medical Instrument Preamp



The low bias currents permit high resistance and low capacitance values to be used to achieve low frequency cutoff. $f_c = 10Hz$, $A_{VCL} = 4$, Passband ripple = 0.1dB

*Note that small capacitors (25-50pF) may be needed for stability in some cases.

Figure 9: Fifth Order Chebyshev Multiple Feedback Low Pass Filter

